Relationship between resist outgassing and activation energy for EUV and EB





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Outline

- Introduction
- Objective of this work
- Experiment & result
 - ✓ Relation between the outgassing and the activation energy of the protecting group
 - ✓ Relation between the outgassing and the quencher loading
- Summary





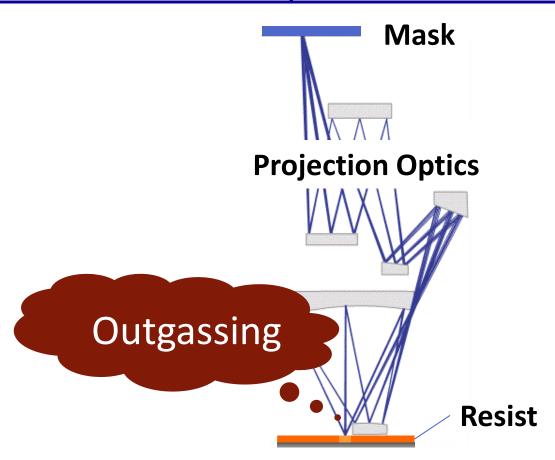
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Resist-induced Optics Contamination

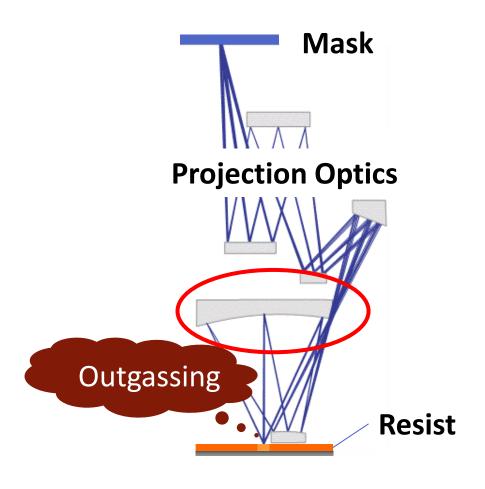


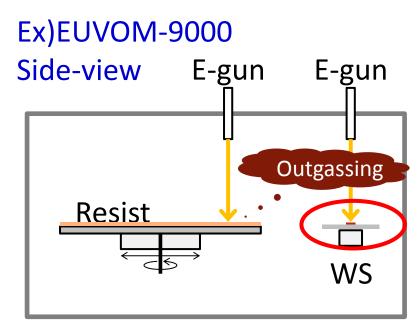
- Outgassing from EUV resist will result in optics contamination.
- Before resists can be used on the EUV scanner, testing by witness sample (WS) method is necessary.





Process Flow of Outgassing Test (WS Method)

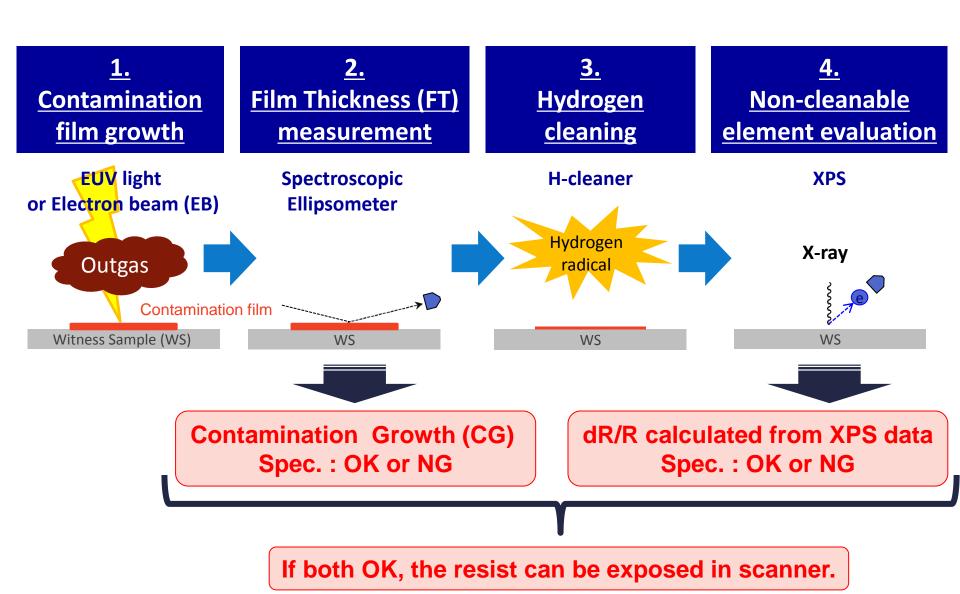








Process Flow of Outgassing Test (WS Method)







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Objective of This Work

- Clarify the relationship between outgassing and the protecting group.
 - ✓ Size of protecting group
 - ✓ Activation energy (Ea) for de-protection

Ex.) Components of model resist

Base resin

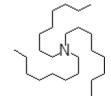
OH

Protecting group

PAG

Û (_}\$⁺ C₄F₉SO₃⁻

Quencher







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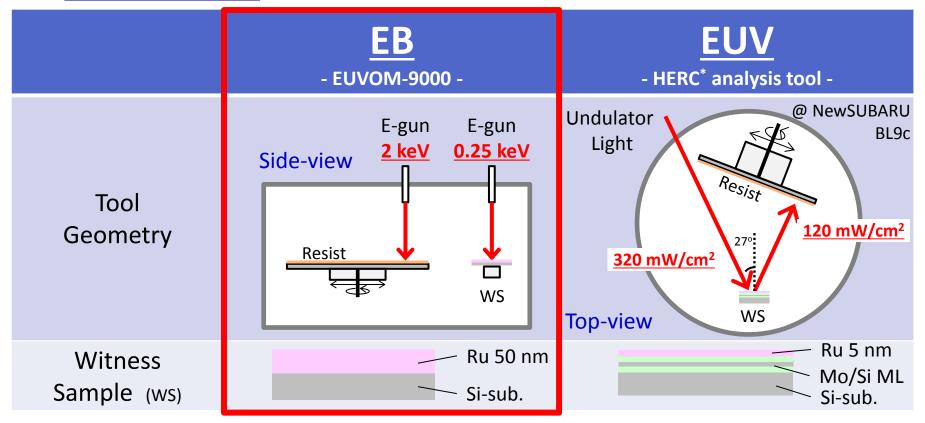
Composition of Model Resists in This Work

Sample name	A-1	B-1	C-1	D-1			
Base resin	0 0 0 O O O O O O O O O O O O O O O O O	00 0 0H	30 O O O O O O O O O O O O O O O O O O O	0 0 0 0 O O O O O O O O O O O O O O O O			
De-protection group (Mw)	148	162	176	82			
Relative acid rate constant (k)	1.0	3.6	12.1	2.9			
PAG	*per hundred resin S+ C ₄ F ₉ SO ₃ - 20 phr*						
Quencher		N	0.1 mol 1	for PAG			



Outgassing Evaluation Tool and Condition

Evaluation tool



Resist process condition

✓ Substrate Si (w/ HMDS)

✓ Resist thickness 60 nm

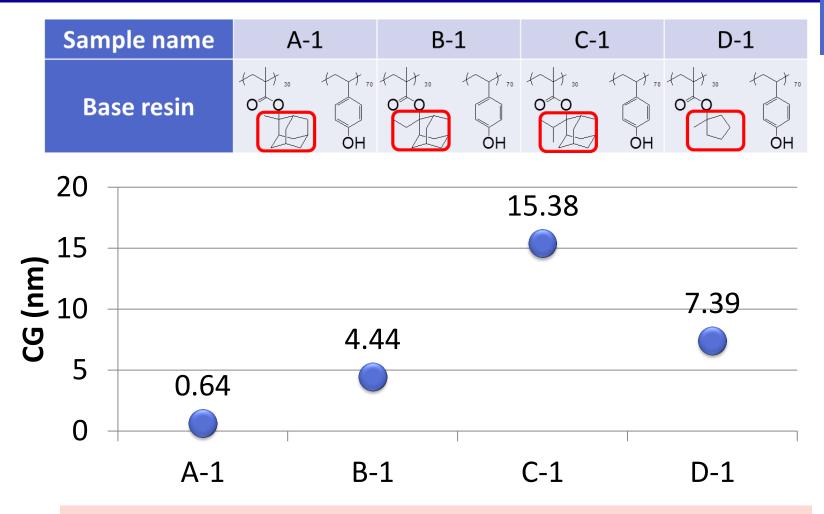
✓ PAB/PEB 100°C 60s / 100°C 60s





*: HERC = **H**igh power **EUV R**esist **C**ontamination

Result of Contamination Growth (CG) Test



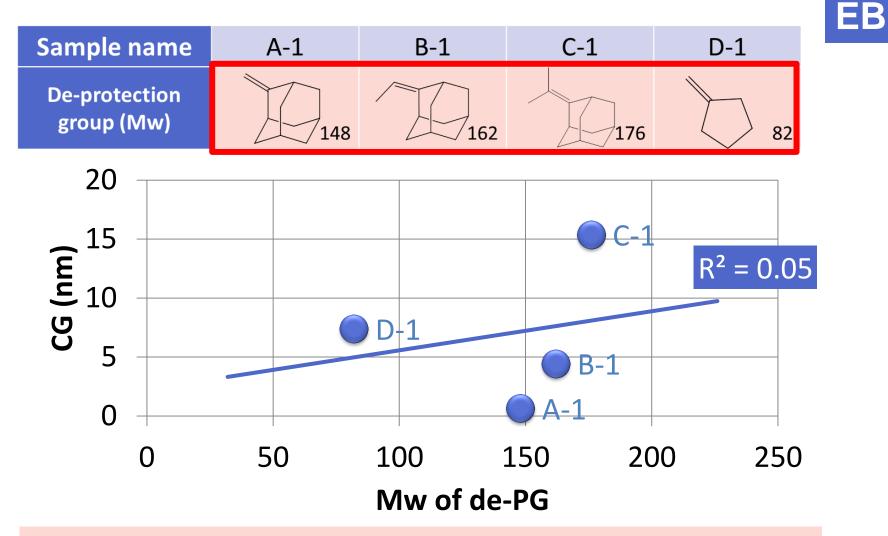
■ Big difference in CG depending on protecting group was observed.

Note: All of CG data is scaled to get to 300 mm full wafer exposure.





CG vs. Size of De-protection Group (De-PG)

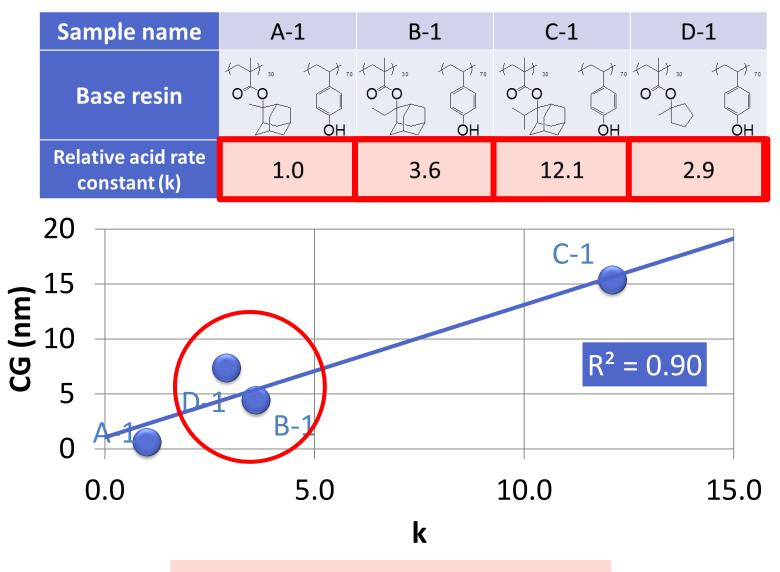


■ No correlation observed between CG and the de-PG size.



EB

Relation between CG and k

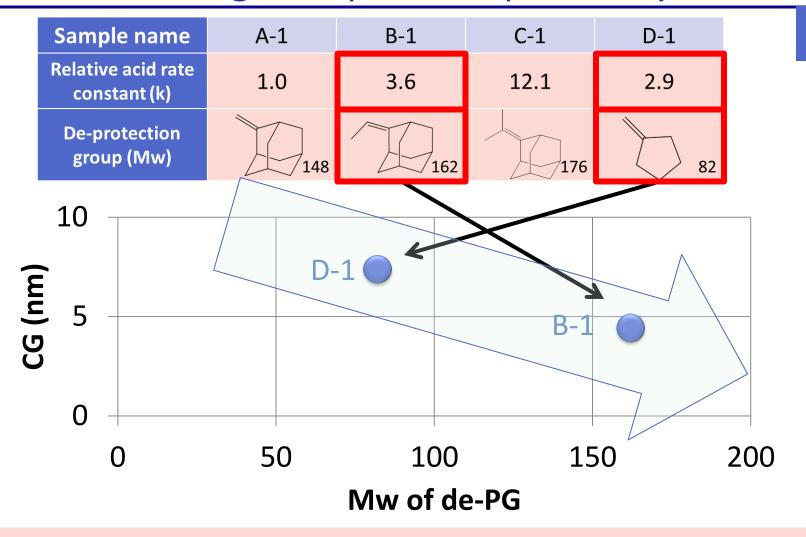


CG seems to correlate with k.



EB

Protecting Group Size Dependency



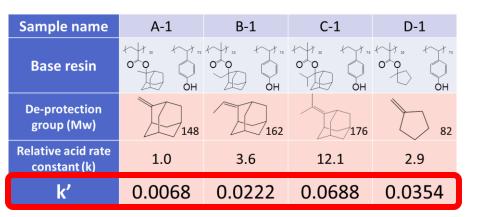
■ In the case of sample with similar acidic reactivity, the larger de-PG was observed to have lower CG.



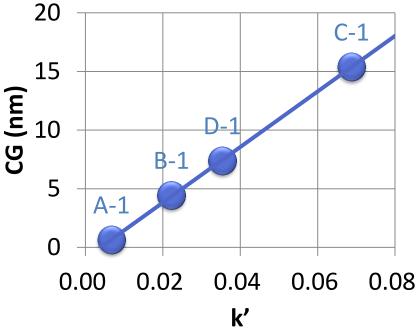


Relation between CG and k'









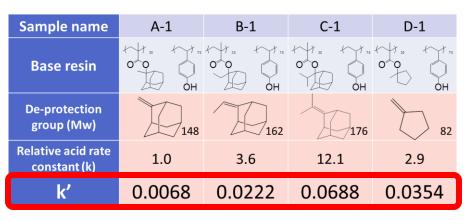
- Considering both k and de-PG size parameters, strong correlation between CG and k' observed.
- This means higher outgassing risk at higher k'.



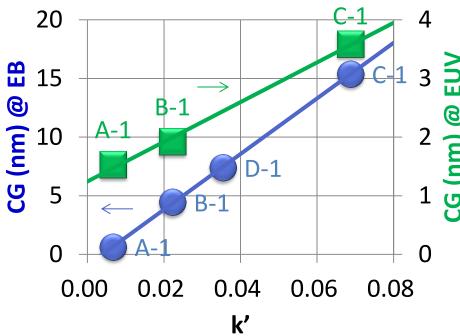


EB vs. EUV

EUV EB



k' = k/(Mw of de-PG)



- EUV based tests confirm that k' can explain the relationship between CG and the characteristics of PGs.
 - ✓ D-1 has not been evaluated at EUV. Future test is planned.





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Composition of Model Resists in This Work

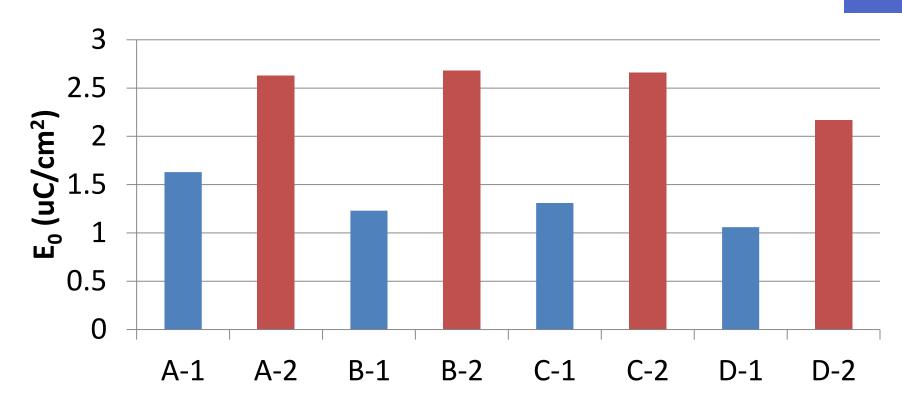
Sample name	A-1 / A-2	B-1 / B-2	C-1 / C-2	D-1 / D-2				
Base resin	0 0 0 0 OH	0 0 O O O O O O O O O O O O O O O O O O	0 0 0 0 OH	0 0 0 70 OH				
De-protection group (Mw)	148	162	176	82				
Relative acid rate constant (k)	1.0	3.6	12.1	2.9				
PAG	*per hundred resin S+ C ₄ F ₉ SO ₃ - 20 phr*							
Quencher								
(mol for PAG)	0.1 / 0.2	0.1 / 0.2	0.1 / 0.2	0.1 / 0.2				





E₀ Sensitivity

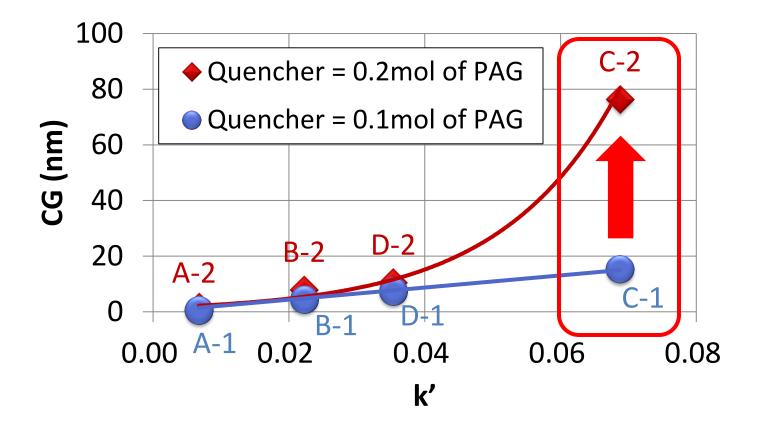
EB



	A-1	A-2	B-1	B-2	C-1	C-2	D-1	D-2
E ₀ (uC/cm ²)	1.63	2.63	1.23	2.68	1.31	2.66	1.06	2.17





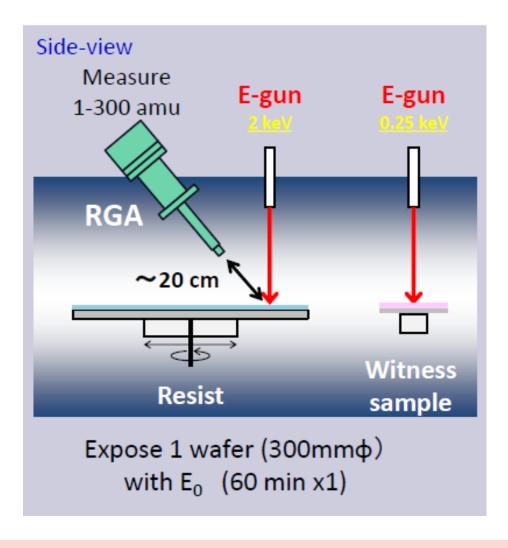


■ Higher CG was found at increased k' and quencher loading.



What's Contributor to CG?



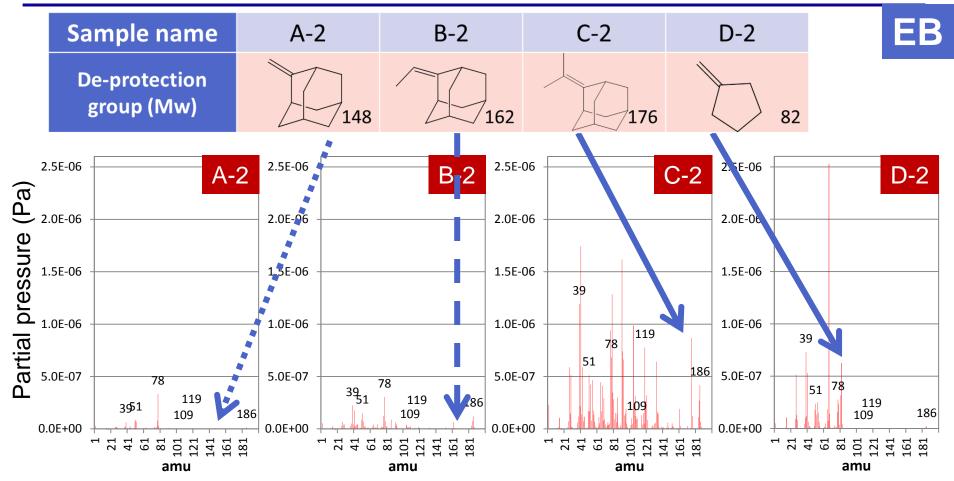


Outgassing species was evaluated by Residual Gas Analysis (RGA)





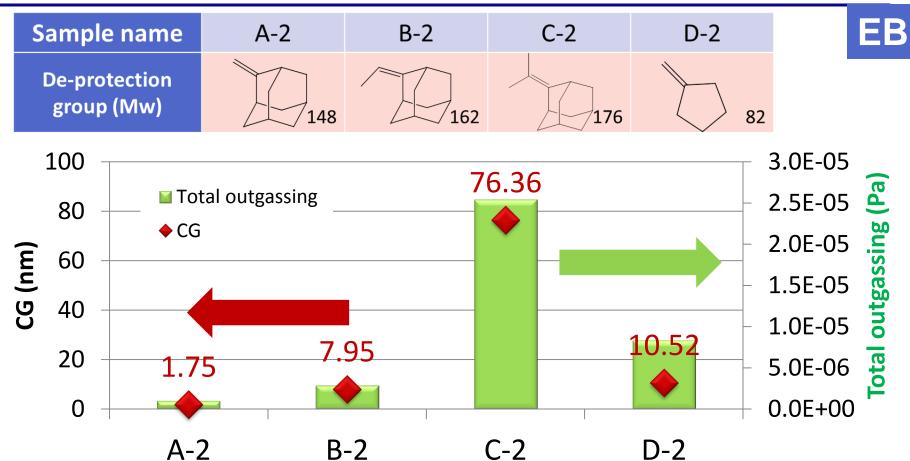
Outgassing Species for Each Samples



- A few species attributed to the de-PG detected at A-2 and B-2.
- Species attributed to the de-PG relatively abundant at C-2 and D-2.
- Numbered amu (39,51,78,109,119 and 186) are attributed to the PAG



Correlation between CG and Total Outgassing

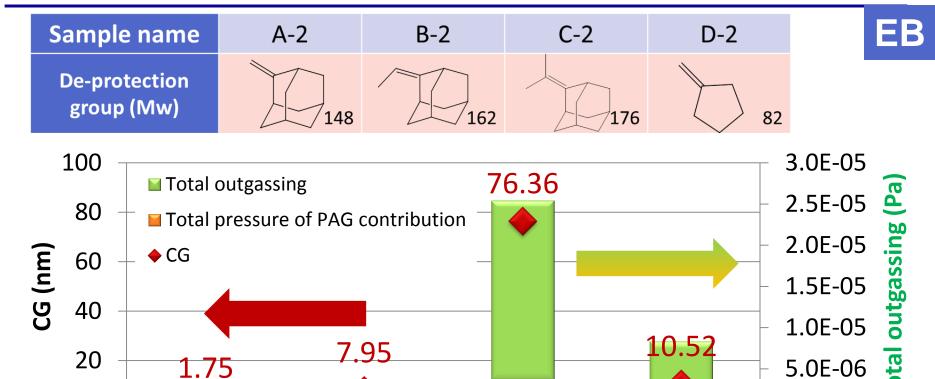


■ CG correlates roughly with total outgassing which is the sum of partial pressures of each amu.





Contributor to CG



■ The main contributor to CG is de-PG species.

B-2



0

A-2

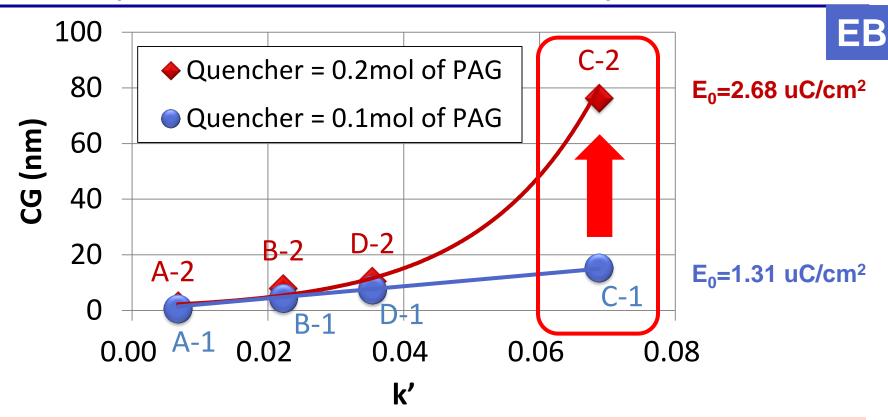


0.0E + 00

D-2

C-2

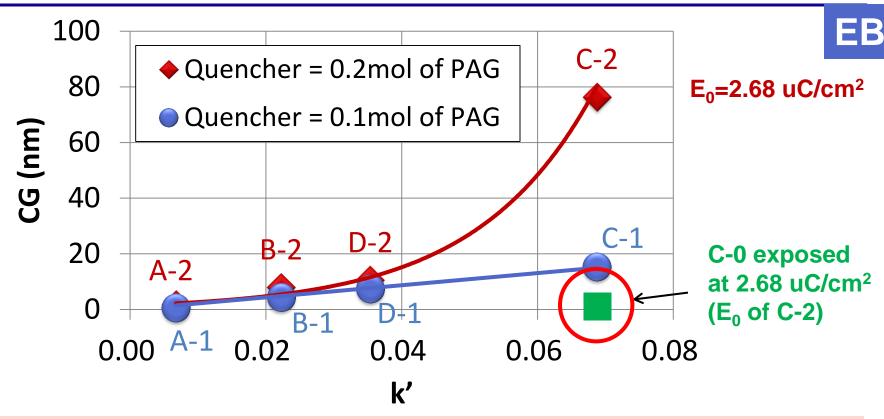
Why the CG Increases Drastically at C-2?



Protecting group was de-protected by the increased dose?



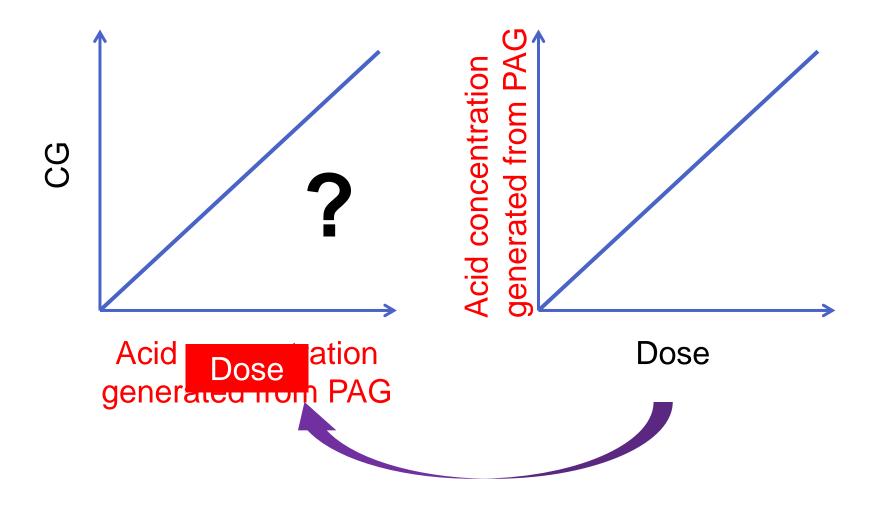
Why the CG Increases Drastically at C-2?



- Protecting group was de-protected by the increased dose?
 - → C-0 (with only base resin) had similar CG to background.
- De-protection reaction is stimulated by acid generated from PAG, and not by the increased dose directly.





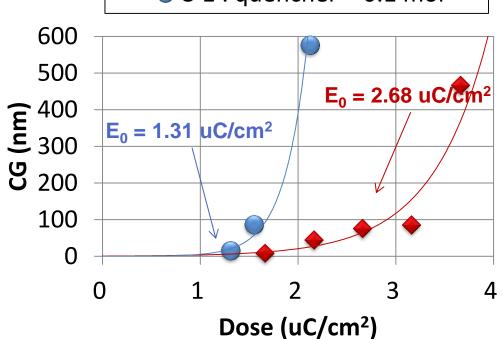






◆ C-2 : quencher = 0.2 mol

C-1 : quencher = 0.1 mol



De-protection reaction equation

$$d[P]/dt = -K_{dp} \cdot [P] \cdot [H^+]^m$$

[P] : normalized PG conc.

[H⁺] : normalized acid conc.

K_{dp} : de-protection rate const.

m : de-protection reaction order

t : time

- CG is not proportional to the dose even while acid concentration is proportional to the dose.
- Assumption: De-protection reaction rate is proportional to the power of acid concentration.





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Summary

- In order to understand the mechanism to mitigate outgassing, the relationship between outgassing and the protecting group was studied.
- Results suggest that the risk of outgassing becomes higher in proportion to k' (= Relative acid rate constant / de-protection group size).
- Good correlation between CG and k' was observed on both EB and EUV.
- Drastic increase of CG confirmed to be mainly due to the de-PG, in a combination of low k' and high quencher loading.





Acknowledgement

This work was supported by New Energy and Industrial Technology Development Organization (NEDO).





Thank you for your kind attention!





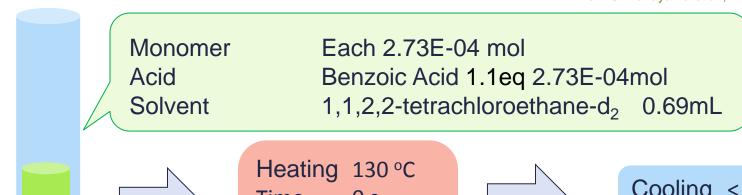
Supporting slide





Analysis of De-Protecion Reaction Kinetics

Ref.: O. Nakayama et.al., Proc. SPIE 6923, 135 (2008).



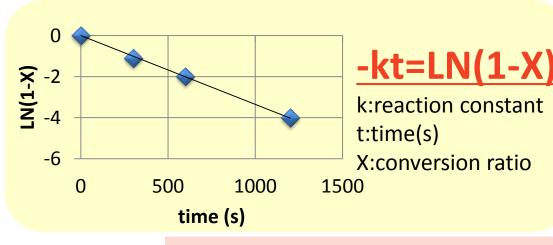
NMR-tube

Heating 130 °C
Time 0 s
300 s
600 s
1200 s



Cooling < 6 °C Time 5 min.





NMR analysis Methacrylic acid Monomer

The reaction conversions were calculated from these integral values.

Large k = high acidic reactivity = Low Ea

